



# BA T46W

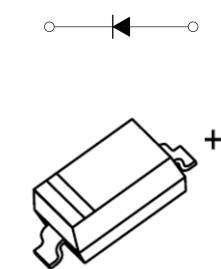
SCHOTTKY BARRIER DIODE

## FEATURES

High breakdown voltage

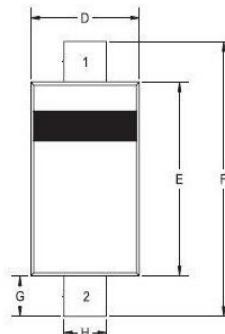
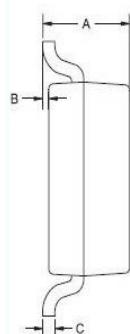
Low turn-on voltage

Guard ring construction for transient protection



SOD-123

SOD123



SYMBOL	DIMENSIONS			
	INCHES	MILLIMETERS	MIN	MAX
A	0,037	0,053	0,95	1,35
B	0,000	0,005	0,00	0,12
C	-	0,008	-	0,20
D	0,055	0,071	1,40	1,80
E	0,098	0,110	2,50	2,80
F	0,142	0,154	3,60	3,90
G	0,016	-	0,40	-
H	0,020	0,028	0,50	0,70

## Maximum Ratings @T<sub>a</sub>=25°C

Parameter	Symbol	Limit	Unit
Peak repetitive peak reverse voltage	V <sub>RRM</sub>	100	V
Working peak reverse voltage	V <sub>RWM</sub>		
Forward continuous current	I <sub>F</sub>	150	mA
Repetitive peak forward current (Note 1) @ tp < 1.0s, Duty Cycle < 50%	I <sub>FRM</sub>	350	mA
Non-repetitive Peak Forward surge current @ t = 8.3ms	I <sub>FSM</sub>	750	mA
Power dissipation	P <sub>D</sub>	500	mW
Thermal resistance junction to ambient air	R <sub>θJA</sub>	200	°C/W
Junction temperature	T <sub>j</sub>	125	°C
Storage temperature	T <sub>STG</sub>	-55~+150	°C

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## ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)

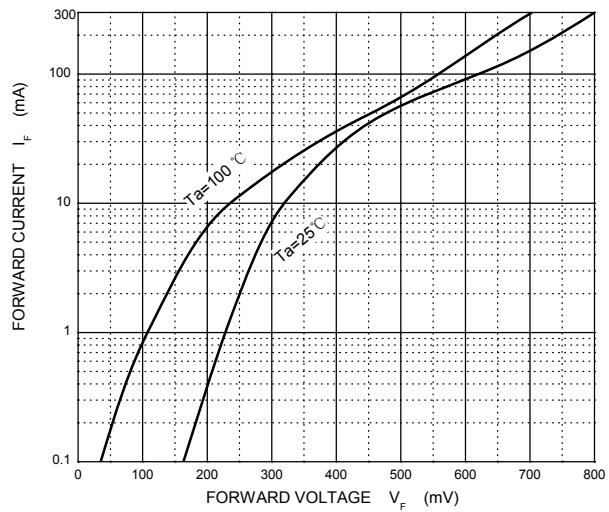
Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Reverse breakdown voltage(Note 2)	V <sub>R</sub>	I <sub>R</sub> = 100μA	100			V
Reverse voltage leakage current	I <sub>R</sub>	V <sub>R1</sub> =1.5V		0.3		μA
		V <sub>R2</sub> =10V		0.5		
		V <sub>R3</sub> =50V		1		
		V <sub>R4</sub> =75V		2		
Forward voltage(Note 2)	V <sub>F</sub>	I <sub>F1</sub> =0.1mA		0.25		V
		I <sub>F2</sub> =10mA		0.45		
		I <sub>F3</sub> =250mA		1		
Diode capacitance	C <sub>T</sub>	V <sub>R</sub> =0, f=1MHz	20			pF
		V <sub>R</sub> =1V, f=1MHz	12			

Notes: 1. Part mounted on FR-4 board with recommended pad layout.

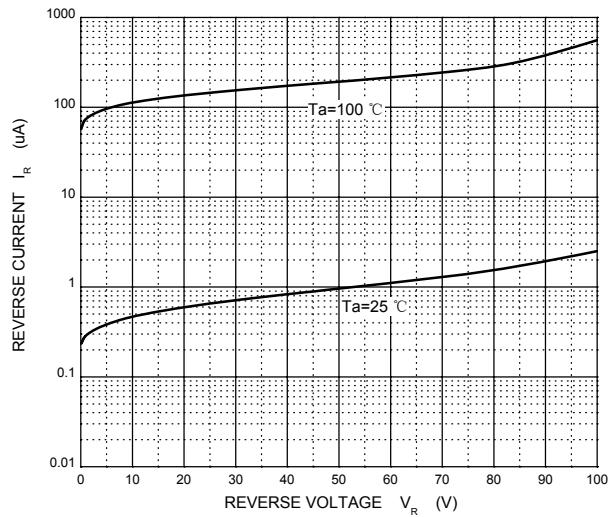
2. Short duration pulse test used to minimize self-heating effect.

## RATING AND CHARACTERISTIC CURVES (BAT46W)

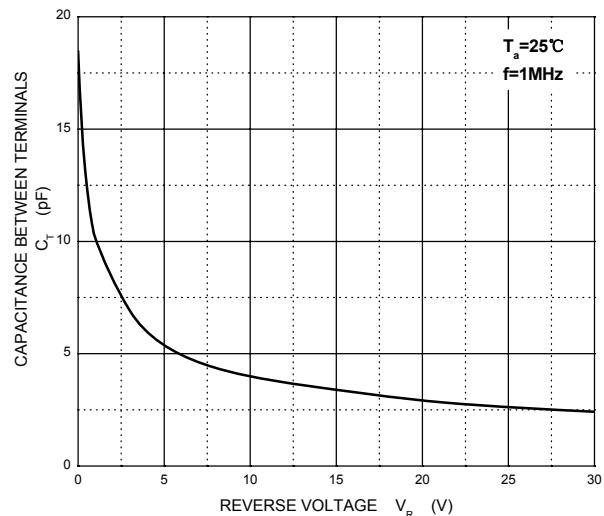
**Forward Characteristics**



**Reverse Characteristics**



**Capacitance Characteristics**



**Power Derating Curve**

